# NSN 5961-01-162-4612

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#### **Inclosure Material:**

Metal

**Overall Length:** 

1.573 inches

# **Overall Height:**

0.300 inches

# **Overall Width:**

1.050 inches

#### **End Application:**

6130-01-059-6948

#### Mounting Facility Quantity:

2

# Internal Configuration:

Junction contact-darlington connected

## Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-3

## Electrode Internally-electrically Connected To Case:

Collector

# Internal Junction Configuration:

Npn

#### **Mounting Method:**

Unthreaded hole

# **Features Provided:**

Hermetically sealed case

#### Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

120.0 collector to emitter voltage/static/base open and 120.0 collector to base voltage, dc and 5.0 emitter to base voltage, instantaneous

#### **Current Rating Per Characteristic:**

50.00 amperes source cutoff current and 125.00 amperes source cutoff current

#### **Power Rating Per Characteristic:**

300.0 watts small-signal input power, common-collector absolute

#### Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

#### **Terminal Type And Quantity:**

1 case and 2 pin

Shelf Life:

N/a

Unit Of Measure:

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#### Demilitarization:

No

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